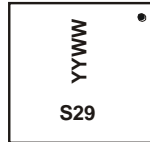


Marking Information



S29 = Product Type Marking Code
YYWW = Date Code Marking
YY = Last Two Digits of Year (ex: 18 = 2018)
WW = Week Code (01 to 53)

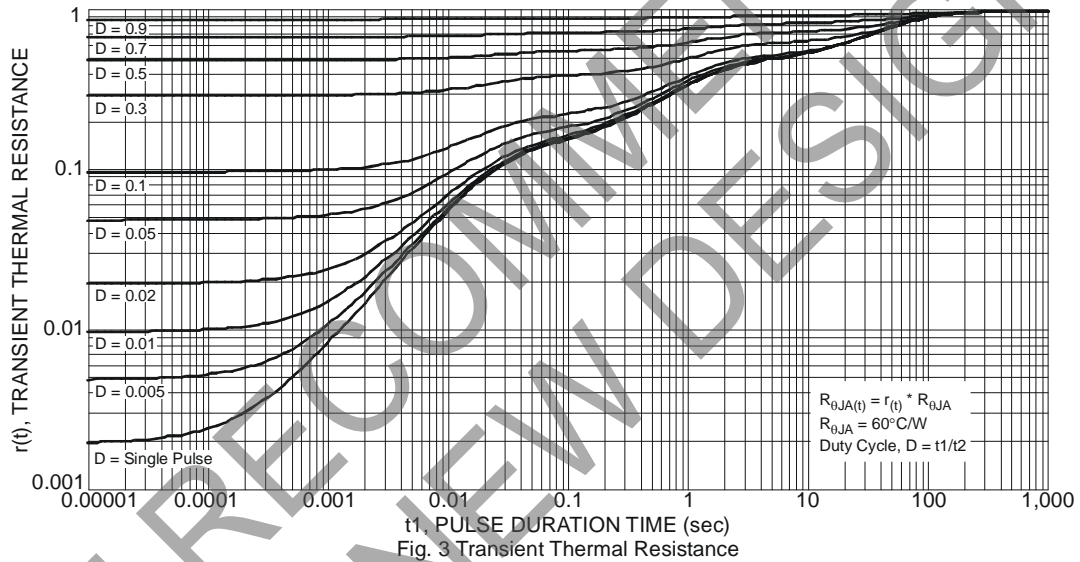
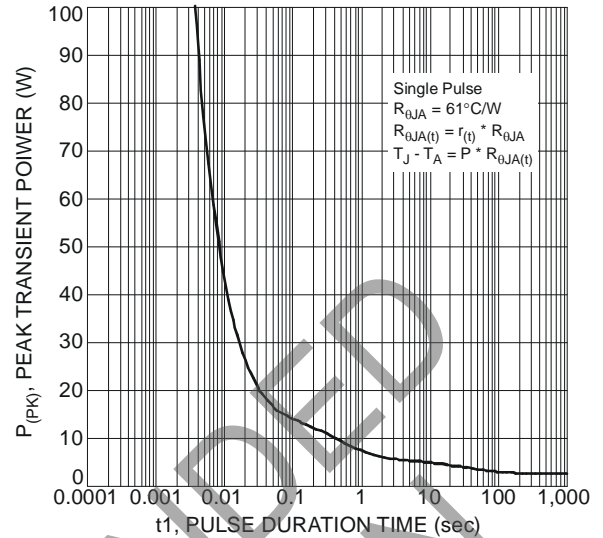
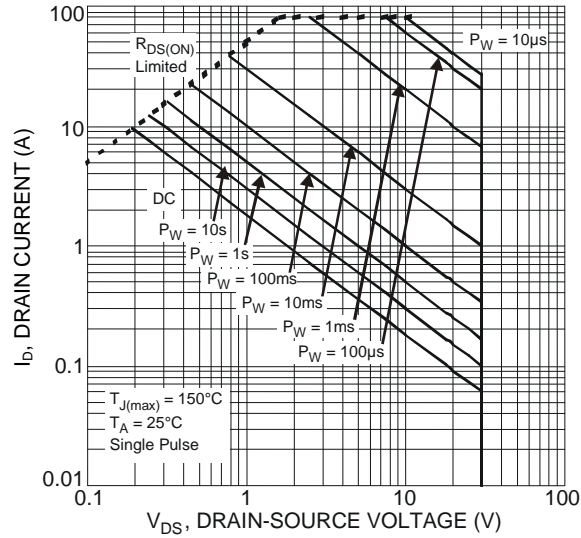
Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			V _{GSS}	±12	V
Continuous Drain Current (Note 6) V _{GS} = 10V	Steady State	T _A = +25°C T _A = +70°C	I _D	9.5 7.6	A
	t < 10s	T _A = +25°C T _A = +70°C	I _D	13.0 9.7	A
Continuous Drain Current (Note 6) V _{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	I _D	9.0 7.4	A
	t < 10s	T _A = +25°C T _A = +70°C	I _D	12.2 9.3	A
Pulsed Drain Current (10μs Pulse, Duty Cycle = 1%)			I _{DM}	80	A
Maximum Continuous Body Diode Forward Current (Note 6)			I _S	3.0	A
Avalanche Current (Note 7) L = 0.1mH			I _{AR}	30	A
Repetitive Avalanche Energy (Note 7) L = 0.1mH			E _{AR}	45	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		P _D	1	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{θJA}	131	°C/W
	t < 10s		72	°C/W
Total Power Dissipation (Note 6)		P _D	2.1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{θJA}	63	°C/W
	t < 10s		35	°C/W
Thermal Resistance, Junction to Case (Note 6)		R _{θJC}	7.1	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
7. I_{AR} and E_{AR} ratings are based on low frequency and duty cycles to keep T_J = +25°C.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	30	—	—	V	V _{GS} = 0V, I _D = 250μA
Zero Gate Voltage Drain Current	I _{DSS}	—	—	100	μA	V _{DS} = 30V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	—	—	±100	nA	V _{GS} = ±12V, V _{DS} = 0V
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	1.0	—	2.2	V	V _{DS} = V _{GS} , I _D = 250μA
Static Drain-Source On-Resistance	R _{DS(ON)}	—	9	13	mΩ	V _{GS} = 10V, I _D = 10.4A
		—	10	14		V _{GS} = 4.5V, I _D = 10.4A
Forward Transfer Admittance	Y _{fs}	—	23	—	S	V _{DS} = 5V, I _D = 10.4A
Diode Forward Voltage	V _{SD}	—	0.4	0.55	V	V _{GS} = 0V, I _S = 1A
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C _{iss}	—	2296	4310	pF	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{oss}	—	164	—	pF	
Reverse Transfer Capacitance	C _{rss}	—	120	—	pF	
Gate Resistance	R _g	0.26	1.3	2.34	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz
Total Gate Charge V _{GS} = 4.5V	Q _g	—	19.3	—	nC	V _{DS} = 15V, V _{GS} = 10V, I _D = 10.4A
Total Gate Charge V _{GS} = 10V	Q _g	—	45.7	—	nC	
Gate-Source Charge	Q _{gs}	—	5.0	—	nC	
Gate-Drain Charge	Q _{gd}	—	2.9	—	nC	
Turn-On Delay Time	t _{D(ON)}	—	5.5	—	ns	V _{GS} = 10V, V _{DS} = 15V, R _G = 3Ω, R _L = 1.2Ω
Turn-On Rise Time	t _R	—	24.4	—	ns	
Turn-Off Delay Time	t _{D(OFF)}	—	33.1	—	ns	
Turn-Off Fall Time	t _F	—	6.6	—	ns	
Reverse Recovery Time	t _{RR}	—	12.9	—	ns	I _F = 13A, di/dt = 500A/μs
Reverse Recovery Charge	Q _{RR}	—	8.0	—	nC	I _F = 13A, di/dt = 500A/μs

Notes: 8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.

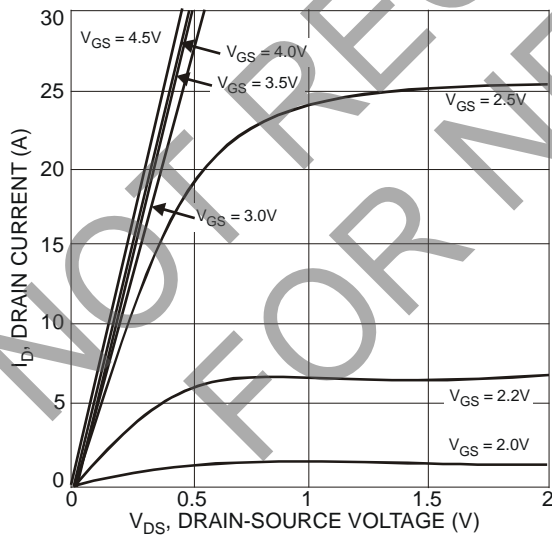


Fig. 4 Typical Output Characteristic

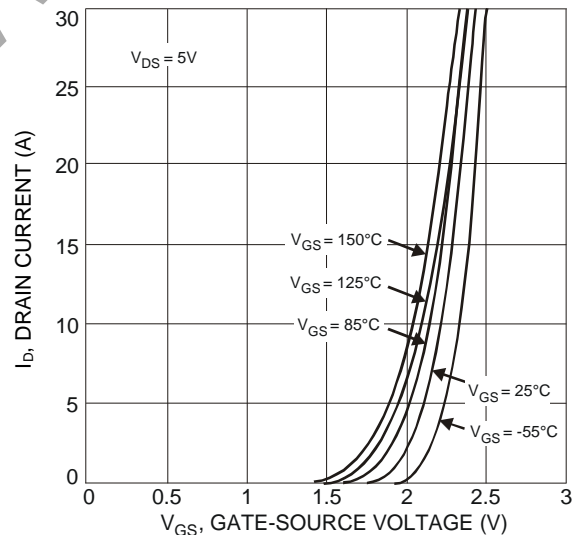
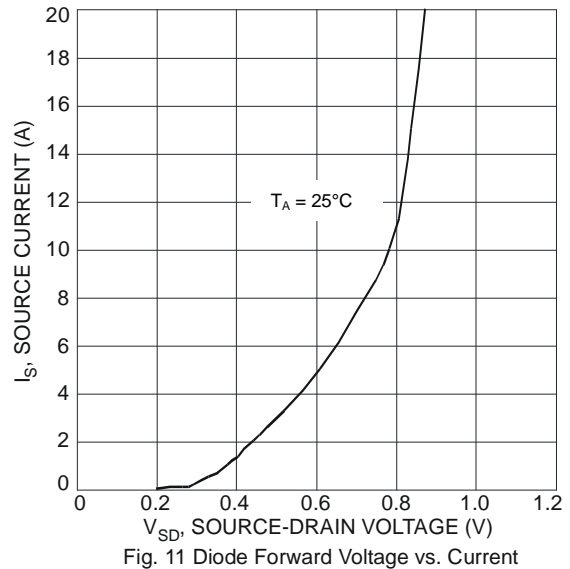
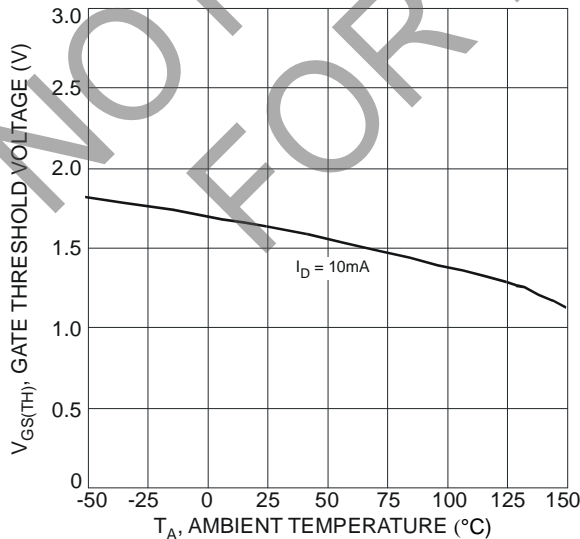
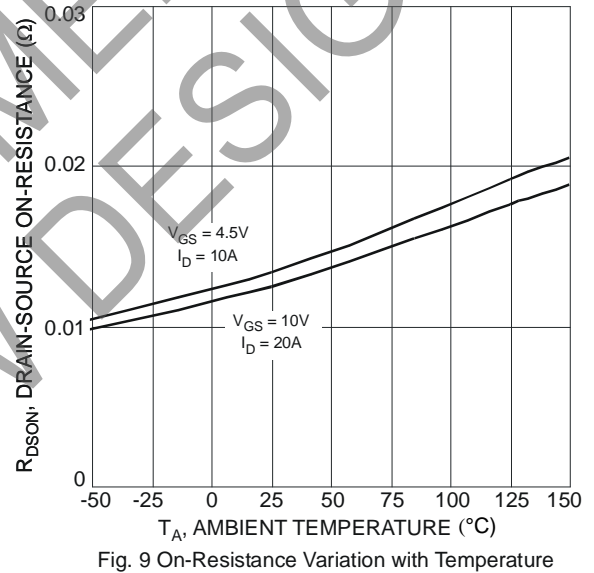
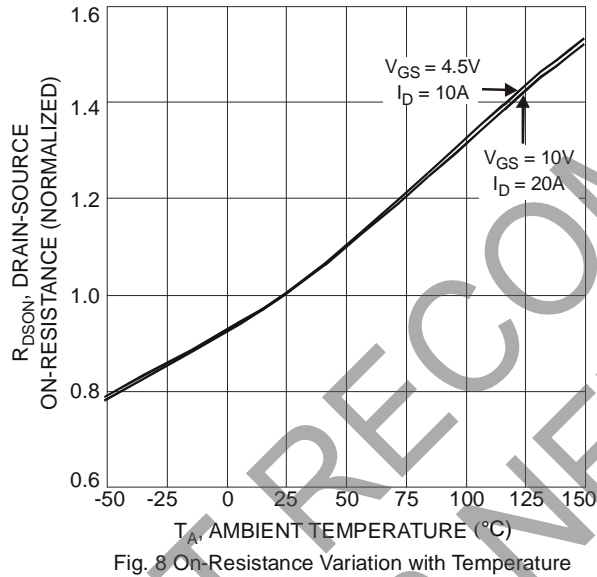
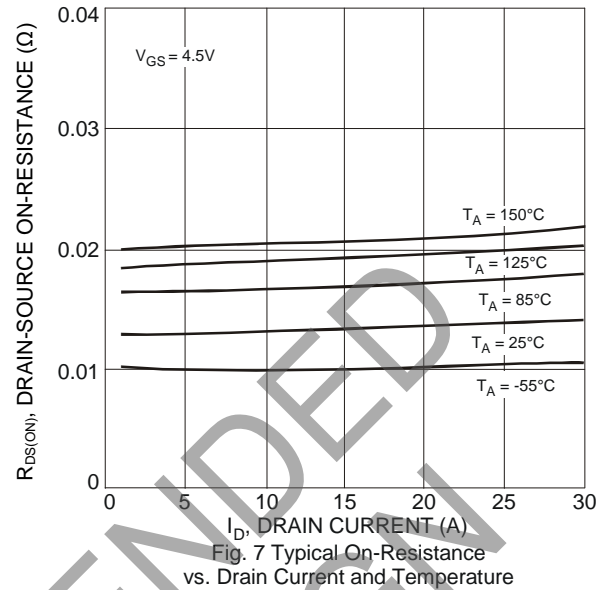
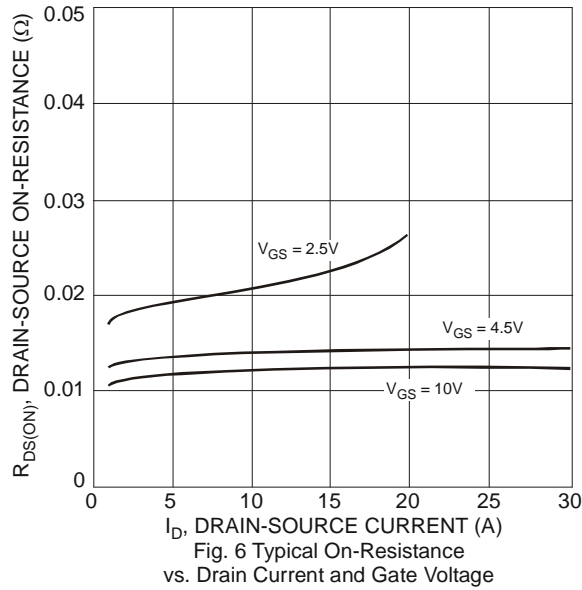


Fig. 5 Typical Transfer Characteristic



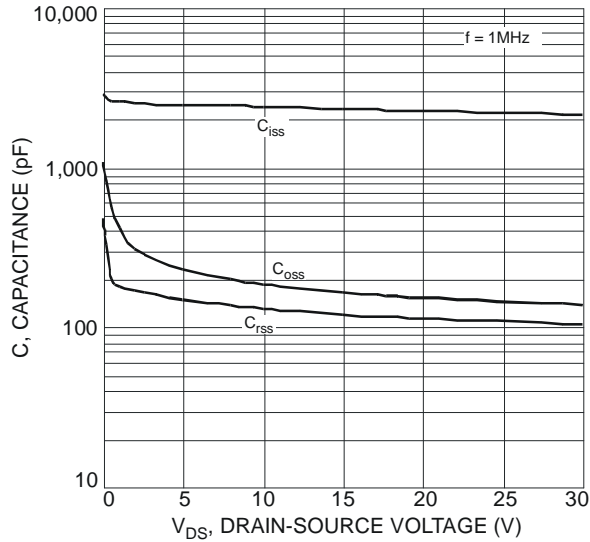


Fig. 12 Typical Total Capacitance

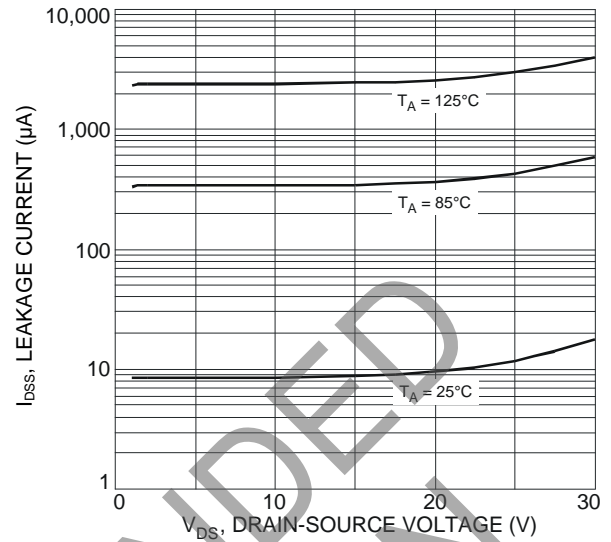


Fig. 13 Typical Leakage Current vs. Drain-Source Voltage

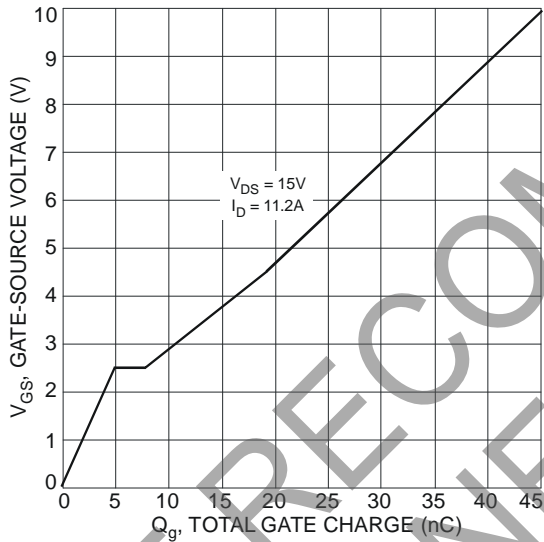
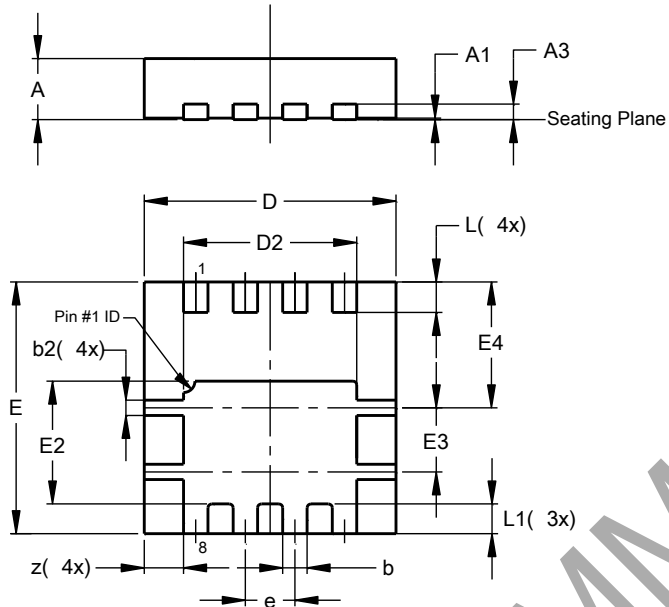


Fig. 14 Gate-Source Voltage vs. Total Gate Charge

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI3333-8

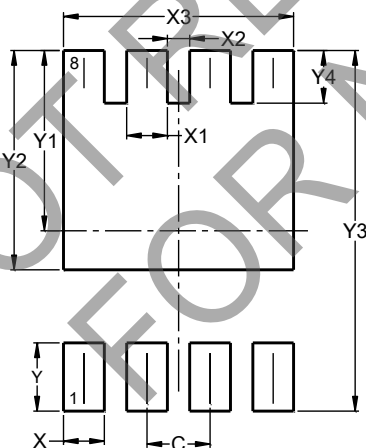


PowerDI3333-8			
Dim	Min	Max	Typ
A	0.75	0.85	0.80
A1	0.00	0.05	0.02
A3	—	—	0.203
b	0.27	0.37	0.32
b2	0.15	0.25	0.20
D	3.25	3.35	3.30
D2	2.22	2.32	2.27
E	3.25	3.35	3.30
E2	1.56	1.66	1.61
E3	0.79	0.89	0.84
E4	1.60	1.70	1.65
e	—	—	0.65
L	0.35	0.45	0.40
L1	—	—	0.39
z	—	—	0.515
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)
C	0.650
X	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540

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